

**UTG60N120FQ-G2**

Preliminary

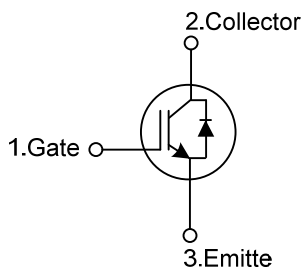
*Insulated Gate Bipolar Transistor***1200V TRENCH GATE
FIELD-STOP IGBT****■ DESCRIPTION**

The UTC **UTG60N120FQ-G2** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG60N120FQ-G2** is suitable for the resonant or soft switching applications.

■ FEATURES

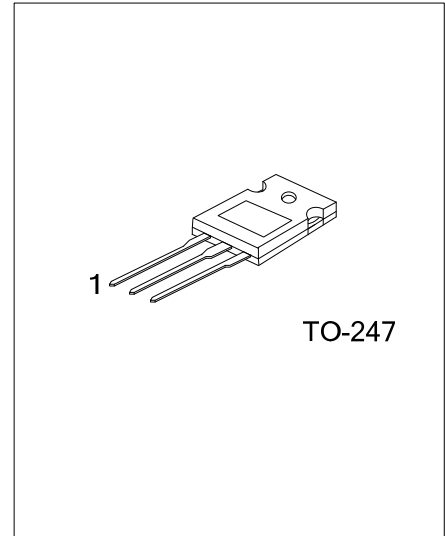
- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT), Typ.} = 1.68V @ I_C=60A, V_{GE}=15V$
($T_C = 25^\circ C$)

■ SYMBOL**■ ORDERING INFORMATION**

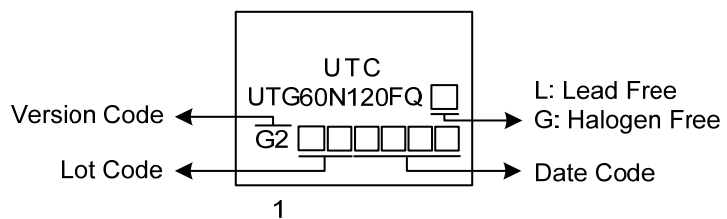
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG60N120FQL-G2-T47-T	UTG60N120FQG-G2-T47-T	TO-247	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG60N120FQG-G2-T47-T	(1)Packing Type (2)Package Type (3)Version Code (4)Green Package	(1) T: Tube (2) T47: TO-247 (3) Version G2 (4) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage		V _{CES}	1200	V
Gate-Emitter Voltage		V _{GES}	±20	V
Transient Gate-emitter voltage (t _p < 5 ms)			±25	V
Continuous Collector Current	T _C =25°C	I _C	120	A
	T _C =100°C		60	A
Collector Current Pulsed (Note 1)		I _{CM}	240	A
Diode Forward Current	T _C =25°C	I _F	72	A
	T _C =100°C		36	A
Short Circuit Withstand Time V _{GE} = 15V, V _{CC} ≤ 200V Allowed number of short circuits < 1000 Time between short circuits: ≥1.0s T _{VJ} = 25°C		t _{SC}	5	μs
Power Dissipation (T _C =25°C)		P _D	285	W
Operating Junction Temperature		T _J	-40 ~ +150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
Absolute maximum ratings are those values beyond which the device could be permanently damaged.
2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ _{JC}	0.44	°C/W

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Off Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V			250	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±250	nA
On Characteristics						
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		6.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =60A, V _{GE} =15V	T _C =25°C	1.68	2.2	V
			T _C =125°C	2.0		V
Dynamic Characteristics						
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		6440		pF
Output Capacitance	C _{OES}			126		pF
Reverse Transfer Capacitance	C _{RES}			63.5		pF
Switching Characteristics						
Total Gate Charge	Q _G	V _{CE} =600V, I _C =60A, V _{GE} =15V		282		nC
Gate-Emitter Charge	Q _{GE}			55		nC
Gate-Collector Charge	Q _{GC}			145		nC
Turn-On Delay Time	t _{DON}	V _{CC} =600V, I _C =60A, R _G =5Ω, V _{GE} =0~15V, L=500μH		37.9		ns
Rise Time	t _R			41.9		ns
Turn-Off Delay Time	t _{DOFF}			256.3		ns
Fall Time	t _F			245.7		ns
Turn-On Switching Loss	E _{ON}			4.258		mJ
Turn-Off Switching Loss	E _{OFF}			5.007		mJ
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Forward Voltage Drop	V _F	I _F =60A			3.5	V
Reverse Recovery Time	t _{rr}	I _F =60A, dI/dt=100A/μS, V _{CC} =400V		63.7		ns
Reverse Recovery Charge	Q _{rr}			1323		nC

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